

Vishay Semiconductors

Small Signal Fast Switching Diode



FEATURESSilicon epita

- Silicon epitaxial planar diode
- Low forward voltage drop
- · High forward current capability
- QuadroMELF package
- AEC-Q101 qualified
- Material categorization:
 For definitions of compliance please see www.vishay.com/doc?99912





MECHANICAL DATA

Case: QuadroMELF SOD-80
Weight: approx. 34 mg
Cathode band color: black
Packaging codes/options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/2.5K per 7" reel (8 mm tape), 12.5K/box

APPLICATIONS

- High speed switch and general purpose
- Use in computer and industrial applications

PARTS TABLE						
PART ORDERING CODE		TYPE MARKING	INTERNAL CONSTRUCTION	REMARKS		
LS4150	LS4150GS18 or LS4150GS08	-	Single diode	Tape and reel		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Repetitive peak reverse voltage		V _{RRM}	50	V		
Reverse voltage		V _R	50	V		
Peak forward surge current	t _p = 1 μs	I _{FSM}	4	Α		
Forward continuous current		I _F	600	mA		
Average forward current	V _R = 0	I _{F(AV)}	300	mA		
Power dissipation		P _{tot}	500	mW		

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Thermal resistance junction to ambient air	On PC board 50 mm x 50 mm x 1.6 mm	R _{thJA}	300	K/W		
Junction temperature		Tj	175	°C		
Storage temperature range		T _{stg}	- 65 to + 175	°C		



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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
	I _F = 1 mA	V _F	540		620	mV
	I _F = 10 mA	V _F	660		740	mV
Forward voltage	$I_F = 50 \text{ mA}$	V _F	760		860	mV
	I _F = 100 mA	V _F	820		920	mV
	I _F = 200 mA	V _F	870		1000	mV
Reverse current	V _R = 50 V	I _R			100	nA
neverse current	V _R = 50 V, T _j = 150 °C	I _R			100	μA
Diode capacitance	V _R = 0, f = 1 MHz, V _{HF} = 50 mV	C _D			2.5	pF
Reverse recovery time	$I_F = I_R = 10 \text{ mA to } 100 \text{ mA},$ $I_R = 0.1 \text{ x } I_R, R_L = 100 \Omega$	t _{rr}			4	ns

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

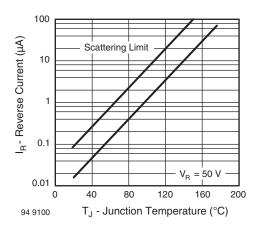


Fig. 1 - Reverse Current vs. Junction Temperature

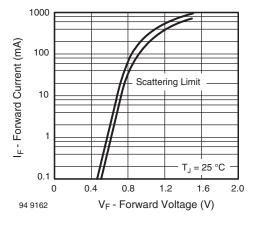
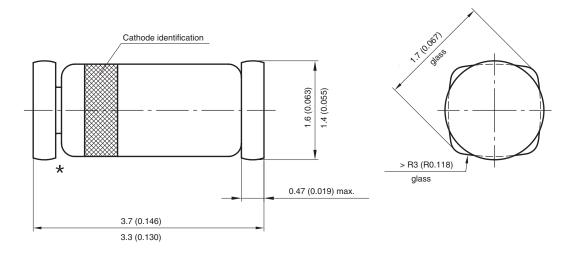


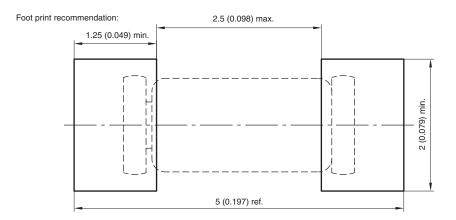
Fig. 2 - Forward Current vs. Forward Voltage

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PACKAGE DIMENSIONS in millimeters (inches): QuadroMELF SOD-80



★ The gap between plug and glass can be either on cathode or anode side



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Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001 Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

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